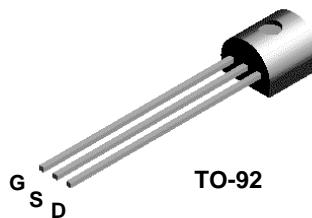
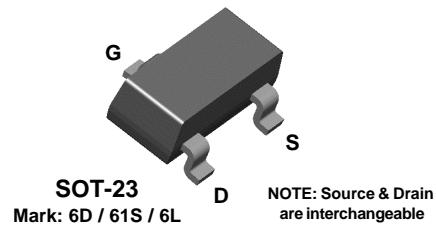




**2N5457  
2N5458  
2N5459**



**MMBF5457  
MMBF5458  
MMBF5459**



## N-Channel General Purpose Amplifier

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	25	V
$V_{GS}$	Gate-Source Voltage	- 25	V
$I_{GF}$	Forward Gate Current	10	mA
$T_J, T_{stg}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		2N5457-5459	*MMBF5457-5459	
$P_D$	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

\* Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

## N-Channel General Purpose Amplifier

(continued)

## Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
<b>OFF CHARACTERISTICS</b>						
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	I <sub>G</sub> = 10 µA, V <sub>DS</sub> = 0	- 25			V
I <sub>GSS</sub>	Gate Reverse Current	V <sub>GS</sub> = -15 V, V <sub>DS</sub> = 0 V <sub>GS</sub> = -15 V, V <sub>DS</sub> = 0, TA = 100°C			- 1.0 - 200	nA nA
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 10 nA	5457	- 0.5	- 6.0	V
			5458	- 1.0	- 7.0	V
			5459	- 2.0	- 8.0	V
V <sub>GS</sub>	Gate-Source Voltage	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 100 µA V <sub>DS</sub> = 15 V, I <sub>D</sub> = 200 µA V <sub>DS</sub> = 15 V, I <sub>D</sub> = 400 µA	5457 5458 5459		- 2.5 - 3.5 - 4.5	V V V

## ON CHARACTERISTICS

I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0	5457	1.0	3.0	5.0	mA
			5458	2.0	6.0	9.0	mA
			5459	4.0	9.0	16	mA

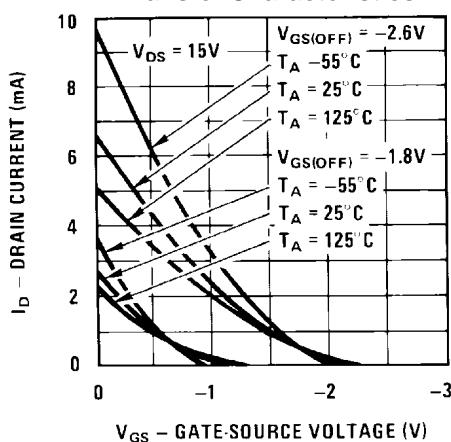
## SMALL SIGNAL CHARACTERISTICS

g <sub>fs</sub>	Forward Transfer Conductance*	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 kHz	5457	1000		5000	µmhos
			5458	1500		5500	µmhos
			5459	2000		6000	µmhos
g <sub>os</sub>	Output Conductance*	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 kHz			10	50	µmhos
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz			4.5	7.0	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz			1.5	3.0	pF
NF	Noise Figure	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 kHz, R <sub>G</sub> = 1.0 megohm, BW = 1.0 Hz				3.0	dB

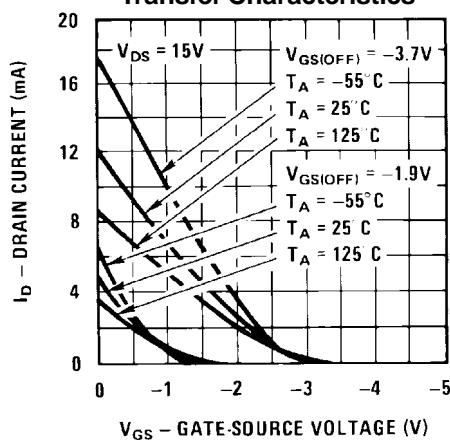
\* Pulse Test: Pulse Width ≤ 300 ms, Duty Cycle ≤ 2%

## Typical Characteristics

## Transfer Characteristics



## Transfer Characteristics

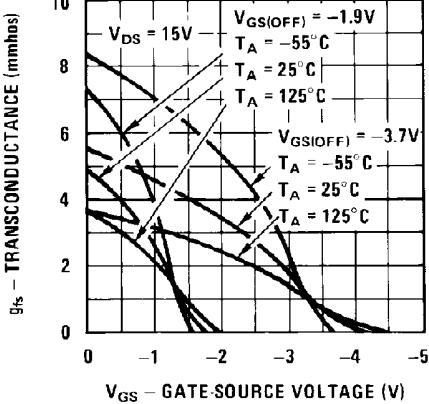


## N-Channel General Purpose Amplifier

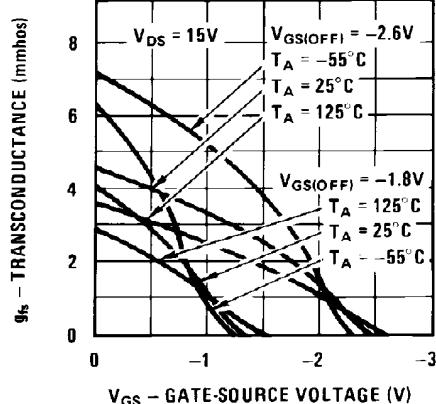
(continued)

### Typical Characteristics (continued)

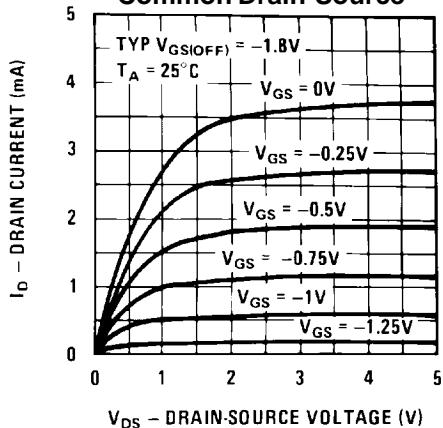
**Transfer Characteristics**



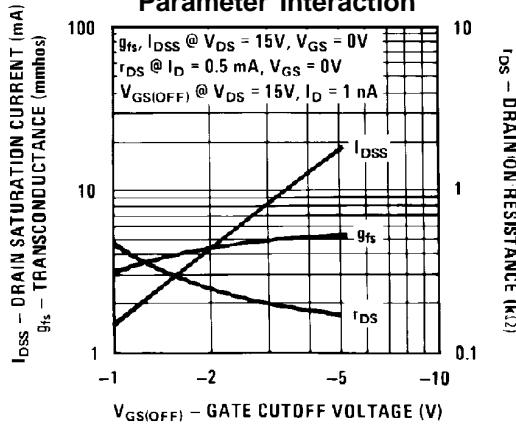
**Transfer Characteristics**



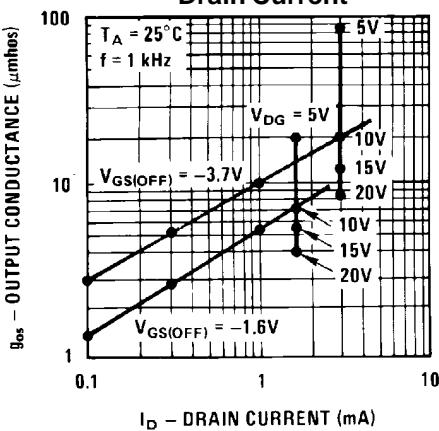
**Common Drain-Source**



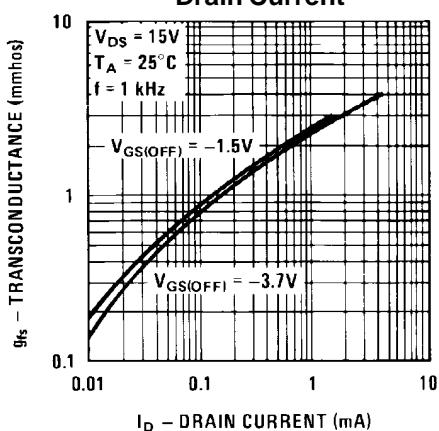
**Parameter Interaction**



**Output Conductance vs. Drain Current**



**Transconductance vs. Drain Current**

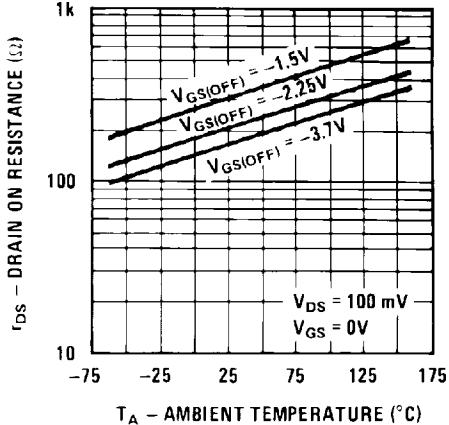


## N-Channel General Purpose Amplifier

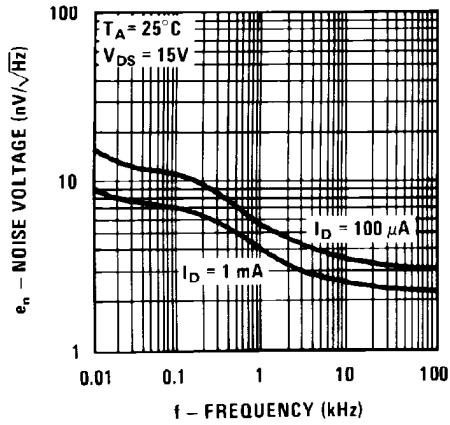
(continued)

### Typical Characteristics (continued)

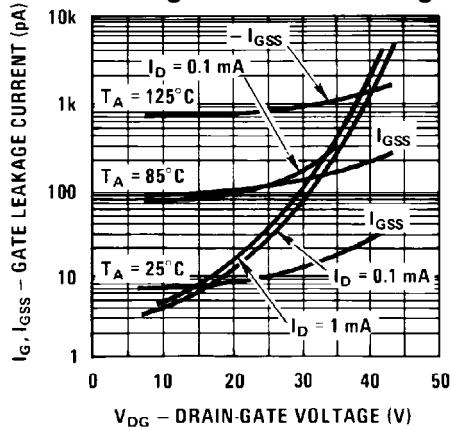
**Channel Resistance vs. Temperature**



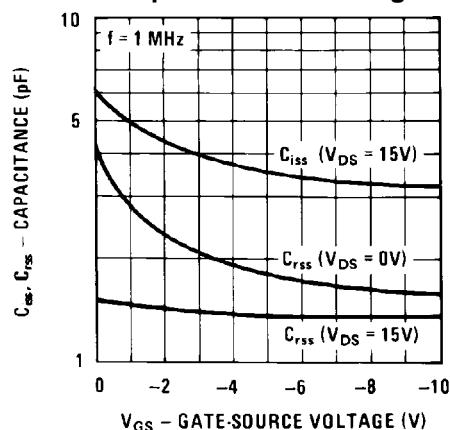
**Noise Voltage vs. Frequency**



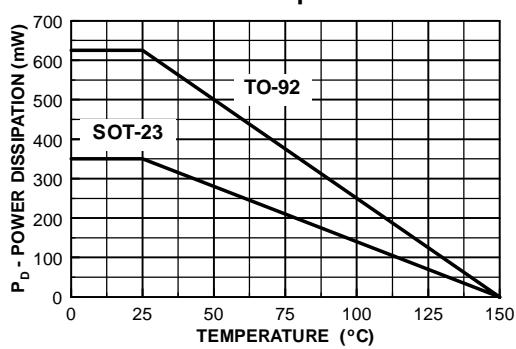
**Leakage Current vs. Voltage**



**Capacitance vs. Voltage**



**Power Dissipation vs. Ambient Temperature**



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